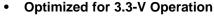


# **LOW-POWER DUAL 2-INPUT POSITIVE-NAND GATE**

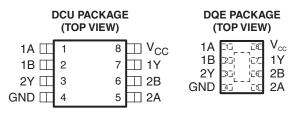
Check for Samples: SN74AUP2G00

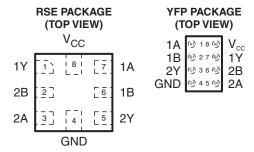
### **FEATURES**

- Available in the Texas Instruments NanoStar™ Package
- Low Static-Power Consumption (I<sub>CC</sub> = 0.9 μA Maximum)
- Low Dynamic-Power Consumption (C<sub>pd</sub> = 4.3 pF Typ at 3.3 V)
- Low Input Capacitance (C<sub>i</sub> = 1.5 pF Typical)
- Low Noise Overshoot and Undershoot <10% of V<sub>CC</sub>
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Wide Operating V<sub>CC</sub> Range of 0.8 V to 3.6 V



- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- t<sub>pd</sub> = 5.9 ns Maximum at 3.3 V
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)

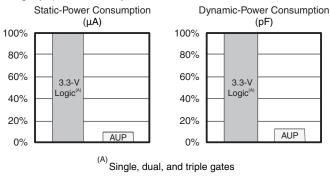


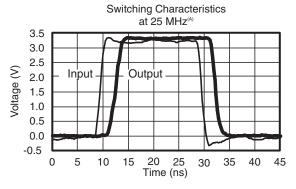


See mechanical drawings for dimensions.

### **DESCRIPTION/ORDERING INFORMATION**

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static- and dynamic-power consumption across the entire  $V_{CC}$  range of 0.8 V to 3.6 V, resulting in increased battery life (see Figure 1). This product also maintains excellent signal integrity (see the very low undershoot and overshoot characteristics shown in Figure 2).





 $^{(A)}$ SN74AUP2Gxx data at C<sub>I</sub> = 15 pF.

Figure 1. AUP – The Lowest-Power Family

Figure 2. Excellent Signal Integrity

A

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



The SN74AUP2G00 performs the Boolean function  $Y = \overline{A \cdot B}$  or  $Y = \overline{A} + \overline{B}$  in positive logic.

NanoStar™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using  $I_{\text{off}}$ . The  $I_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE <sup>(1)</sup> (2)		ORDERABLE PART NUMBER	TOP-SIDE MARKING (3)
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YFP (Pb-free)	Reel of 3000	SN74AUP2G00YFPR	HA_
-40°C to 85°C	uQFN – DQE	Reel of 5000	SN74AUP2G00DQER	PN
	QFN - RSE	Reel of 5000	SN74AUP2G00RSER	PN
	SSOP - DCU	Reel of 3000	SN74AUP2G00DCUR	H00_

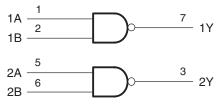
- (1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
- (3) DCU: The actual top-side marking has one additional character that designates the wafer fab/assembly site.

  YFP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, = Pb-free).

### **FUNCTION TABLE**

INP	UTS	OUTPUT
Α	В	Y
L	L	Н
L	Χ	Н
Х	L	Н
Н	Н	L

### **LOGIC DIAGRAM (POSITIVE LOGIC)**



Pin number shown are for DCU and DQE packages.



### ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V
VI	Input voltage range <sup>(2)</sup>			4.6	V
Vo	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>			4.6	V
Vo	Output voltage range in the high or low stat	re <sup>(2)</sup>	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
Io	Continuous output current			±20	mA
	Continuous current through V <sub>CC</sub> or GND			±50	mA
		DCU package		220	°C/W
0	Deal (3)	DQE package		261	
$\theta_{JA}$	Package thermal impedance (3)	RSE package		253	
		YFP package		132	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Submit Documentation Feedback

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> The package thermal impedance is calculated in accordance with JESD 51-7.



# RECOMMENDED OPERATING CONDITIONS(1)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage		0.8	3.6	V	
		V <sub>CC</sub> = 0.8 V	V <sub>CC</sub>			
.,	High lavel ignest valtage	V <sub>CC</sub> = 1.1 V to 1.95 V	0.65 × V <sub>CC</sub>		V	
$V_{IH}$	High-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	1.6		V	
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2			
		V <sub>CC</sub> = 0.8 V		0		
V	Low level input valtage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	V	
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V		0.7	V	
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		0.9		
VI	Input voltage		0	3.6	V	
Vo	Output voltage		0	$V_{CC}$	V	
	Ulah laval avtast avesat	V <sub>CC</sub> = 0.8 V		-20	μА	
		V <sub>CC</sub> = 1.1 V		-1.1		
ı		V <sub>CC</sub> = 1.4 V		-1.7		
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 1.65		-1.9	mA	
		$V_{CC} = 2.3 \text{ V}$		-3.1		
		V <sub>CC</sub> = 3 V		-4		
		V <sub>CC</sub> = 0.8 V		20	μΑ	
		V <sub>CC</sub> = 1.1 V		1.1		
	Low-level output current	V <sub>CC</sub> = 1.4 V		1.7		
l <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 1.65 V		1.9		
		V <sub>CC</sub> = 2.3 V				
		$V_{CC} = 3 V$		4		
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$		200	ns/V	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C	

<sup>(1)</sup> All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. See the TI application report *Implications* of Slow or Floating CMOS Inputs, literature number SCBA004.



### **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	V	T,	<sub>A</sub> = 25°C	T <sub>A</sub> = -40°C	to 85°C	UNIT	
PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP MAX	MIN	MAX	UNII	
	$I_{OH} = -20 \mu A$	0.8 V to 3.6 V	V <sub>CC</sub> - 0.1		V <sub>CC</sub> - 0.1			
	I <sub>OH</sub> = -1.1 mA	1.1 V	0.75 × V <sub>CC</sub>		$0.7 \times V_{CC}$			
	$I_{OH} = -1.7 \text{ mA}$	1.4 V	1.11		1.03			
\ /	I <sub>OH</sub> = -1.9 mA	1.65 V	1.32		1.3		.,	
$V_{OH}$	$I_{OH} = -2.3 \text{ mA}$	221/	2.05		1.97		V	
	$I_{OH} = -3.1 \text{ mA}$	2.3 V	1.9		1.85			
	$I_{OH} = -2.7 \text{ mA}$	2.1/	2.72		2.67			
	$I_{OH} = -4 \text{ mA}$	3 V	2.6		2.55			
	I <sub>OL</sub> = 20 μA	0.8 V to 3.6 V		0.1		0.1		
	I <sub>OL</sub> = 1.1 mA	1.1 V		0.3 × V <sub>CC</sub>		0.3 × V <sub>CC</sub>		
	I <sub>OL</sub> = 1.7 mA	1.4 V		0.31		0.37		
	I <sub>OL</sub> = 1.9 mA	1.65 V		0.31		0.35	V	
$V_{OL}$	I <sub>OL</sub> = 2.3 mA	0.01/		0.31		0.33	V	
	I <sub>OL</sub> = 3.1 mA	2.3 V		0.44		0.45		
	I <sub>OL</sub> = 2.7 mA	2.1/		0.31		0.33		
	I <sub>OL</sub> = 4 mA	3 V		0.44		0.45		
I <sub>I</sub> A or B input	$V_I = GND \text{ to } 3.6 \text{ V}$	0 V to 3.6 V		0.1		0.5	μΑ	
l <sub>off</sub>	$V_I$ or $V_O = 0$ V to 3.6 V	0 V		0.2		0.6	μΑ	
$\Delta I_{ m off}$	$V_I$ or $V_O = 0$ V to 3.6 V	0 V to 0.2 V		0.2		0.6	μΑ	
I <sub>cc</sub>	$V_I = GND \text{ or } (V_{CC} \text{ to } 3.6 \text{ V}),$ $I_O = 0$	0.8 V to 3.6 V		0.5		0.9	μА	
ΔI <sub>CC</sub>	$V_I = V_{CC} - 0.6 V^{(1)},$ $I_O = 0$	3.3 V		40		50	μА	
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	0 V		1.5			pF	
C <sub>o</sub>	V <sub>O</sub> = GND	3.6 V 0 V		3			pF	

<sup>(1)</sup> One input at  $V_{CC} - 0.6 \text{ V}$ , other input at  $V_{CC}$  or GND

### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range,  $C_L = 5 pF$  (unless otherwise noted) (see Figure 3 and Figure 4)

			, F I ,			, ,	•	•	,
DADAMETED	FROM	то	V	T,	<sub>A</sub> = 25°C	;	$T_A = -40^{\circ}C$	to 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	UNIT
	A or B		0.8 V		19.8				
			1.2 V ± 0.1 V	2.6	7.8	18.8	2.1	19.8	
			1.5 V ± 0.1 V	1.4	5.4	11.8	0.9	13.9	
t <sub>pd</sub>		Ť	1.8 V ± 0.15 V	1	4.3	9	0.5	11.1	ns
			2.5 V ± 0.2 V	1	3	5.9	0.5	7.8	
		3.3 V ± 0.3 V	1	2.4	4.9	0.5	5.9		

Product Folder Link(s): SN74AUP2G00



### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range,  $C_L = 10 \text{ pF}$  (unless otherwise noted) (see Figure 3 and Figure 4)

DADAMETED	FROM	то	V	T,	<sub>λ</sub> = 25°C	;	$T_A = -40^{\circ}C$	to 85°C	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	ONIT	
			0.8 V		23.1					
			1.2 V ± 0.1 V	1.5	8.9	21.1	1	22		
	A or D		1.5 V ± 0.1 V	1	6.3	13.2	0.5	15.1	20	
t <sub>pd</sub>	A or B	Y	1.8 V ± 0.15 V	1	5	10.1	0.5	12.2	ns	
			2.5 V ± 0.2 V	1	3.6	7.4	0.5	9		
			3.3 V ± 0.3 V	1	2.9	5.2	0.5	6.5		

### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range, C<sub>L</sub> = 15 pF (unless otherwise noted) (see Figure 3 and Figure 4)

DADAMETER	FROM	то	V	T,	4 = 25°C	;	T <sub>A</sub> = -40°C	to 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	UNII
		V	0.8 V		24.7				
			1.2 V ± 0.1 V	3.6	9.8	21.7	3.1	22.7	
4	A or B		1.5 V ± 0.1 V	2.3	4.6	14	1.8	15.7	
t <sub>pd</sub>	AOIB	Ť	1.8 V ± 0.15 V	1.6	5.5	10.6	1.1	12.6	ns
			2.5 V ± 0.2 V	1	4	7	0.5	8.9	
			3.3 V ± 0.3 V	1	3.3	5.6	0.5	6.9	

### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range,  $C_L = 30 \text{ pF}$  (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	Vaa	T,	<sub>A</sub> = 25°C		T <sub>A</sub> = -40°C	to 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	ONII
			0.8 V		31.8				
		V	1.2 V ± 0.1 V	4.9	12.6	26.3	4.4	27	
	A or B			1.5 V ± 0.1 V	3.4	9	16.6	2.9	18.3
t <sub>pd</sub>	AUIB	T	1.8 V ± 0.15 V	2.5	7.3	12.9	2	14.8	ns
			2.5 V ± 0.2 V	1.8	5.4	8.8	1.3	10.5	
			3.3 V ± 0.3 V	1.5	4.5	6.7	1	8.2	

### **OPERATING CHARACTERISTICS**

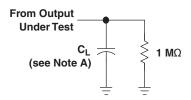
 $T_{\Delta} = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	TYP	UNIT
			0.8 V	4	
			1.2 V ± 0.1 V	4	
0	Dower dissination conscitance	f 40 MH=	1.5 V ± 0.1 V	4	
$C_{pd}$	Power dissipation capacitance	f = 10 MHz	1.8 V ± 0.15 V	4	pF
			2.5 V ± 0.2 V	4.1	
			3.3 V ± 0.3 V	4.3	

Submit Documentation Feedback

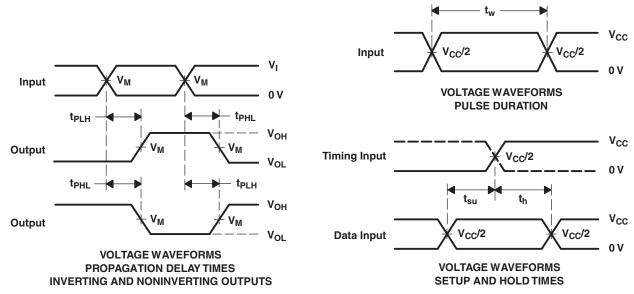


# PARAMETER MEASUREMENT INFORMATION (Propagation Delays, Setup and Hold Times, and Pulse Width)



**LOAD CIRCUIT** 

	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V ± 0.1 V	V <sub>CC</sub> = 1.5 V ± 0.1 V	$V_{CC}$ = 1.8 V $\pm$ 0.15 V	$V_{CC}$ = 2.5 V $\pm$ 0.2 V	$V_{CC}$ = 3.3 V $\pm$ 0.3 V
C <sub>L</sub>	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V <sub>M</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2
V <sub>I</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>

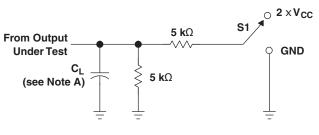


- A. C<sub>L</sub> includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ , for propagation delays  $t_t/t_f = 3$  ns, for setup and hold times and pulse width  $t_t/t_f = 1.2$  ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- F. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



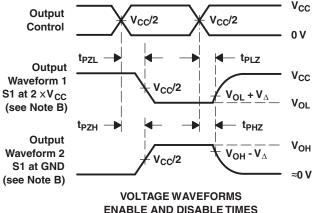
# PARAMETER MEASUREMENT INFORMATION (Enable and Disable Times)



TEST	S1
t <sub>PLZ</sub> /t <sub>PZL</sub>	2×V <sub>CC</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

LOAD CIRCUIT

	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V ± 0.1 V	V <sub>CC</sub> = 1.5 V ± 0.1 V	$V_{CC}$ = 1.8 V $\pm$ 0.15 V	$V_{CC}$ = 2.5 V $\pm$ 0.2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V
C <sub>L</sub> V <sub>M</sub> V <sub>I</sub> V <sub>∆</sub>	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2
	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>
	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



- ENABLE AND DISABLE TIMES LOW- AND HIGH-LEVEL ENABLING
- A. C<sub>L</sub> includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \ \Omega$ ,  $t_r/t_f = 3 \ ns$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms

### PACKAGE OPTION ADDENDUM

www.ti.com 27-Apr-2010

### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN74AUP2G00DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP2G00DQER	ACTIVE	X2SON	DQE	8	5000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM
SN74AUP2G00RSER	ACTIVE	UQFN	RSE	8	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP2G00YFPR	ACTIVE	DSBGA	YFP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

### PACKAGE MATERIALS INFORMATION

www.ti.com 8-Jul-2011

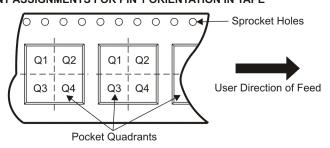
### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



### \*All dimensions are nominal

All dimensions are nominal												
Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP2G00DCUR	US8	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74AUP2G00DQER	X2SON	DQE	8	5000	180.0	8.4	1.17	1.67	0.73	4.0	8.0	Q1
SN74AUP2G00RSER	UQFN	RSE	8	5000	180.0	8.4	1.6	1.6	0.66	4.0	8.0	Q2
SN74AUP2G00YFPR	DSBGA	YFP	8	3000	178.0	9.2	0.9	1.75	0.6	4.0	8.0	Q1

www.ti.com 8-Jul-2011



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP2G00DCUR	US8	DCU	8	3000	202.0	201.0	28.0
SN74AUP2G00DQER	X2SON	DQE	8	5000	202.0	201.0	28.0
SN74AUP2G00RSER	UQFN	RSE	8	5000	202.0	201.0	28.0
SN74AUP2G00YFPR	DSBGA	YFP	8	3000	220.0	220.0	35.0

# DCU (R-PDSO-G8)

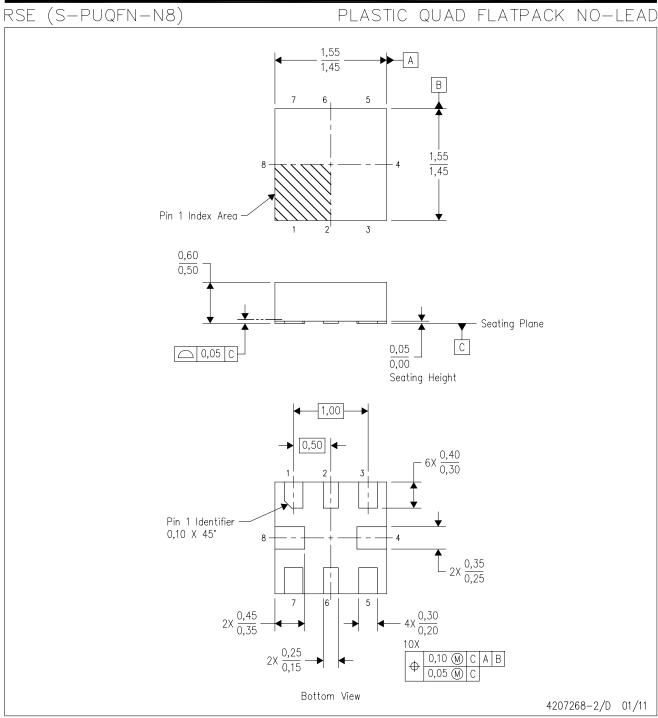
# PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES:

- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-187 variation CA.





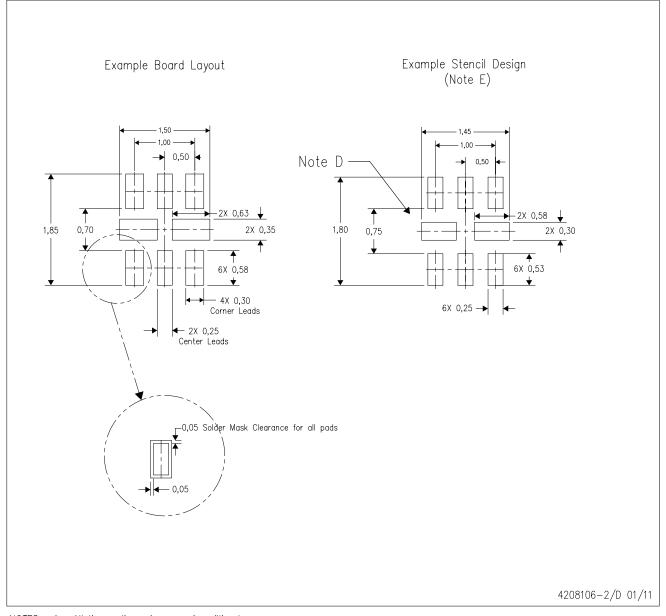
NOTES: All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
  C. QFN (Quad Flatpack No-Lead) package configuration.
  D. This package complies to JEDEC MO-288 variation UECD.



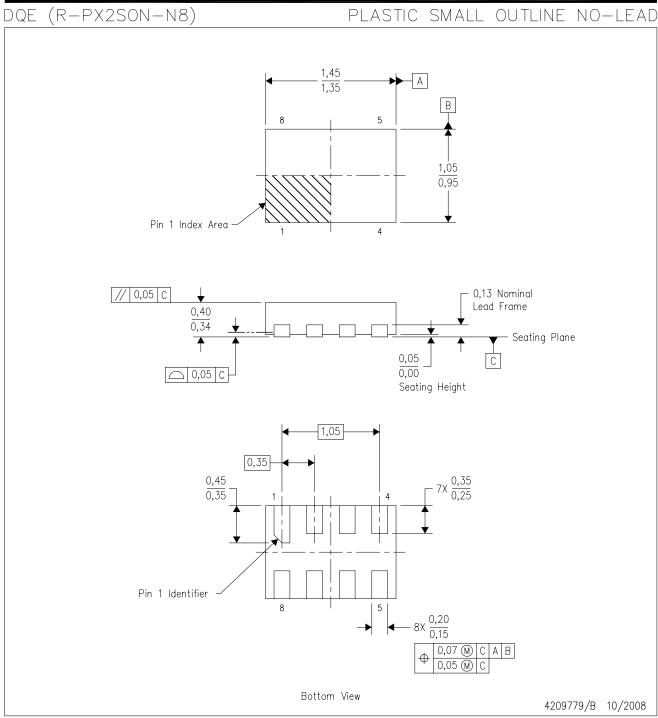
# RSE (S-PUQFN-N8)

### PLASTIC QUAD FLATPACK NO-LEAD



- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
  - E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
  - F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.





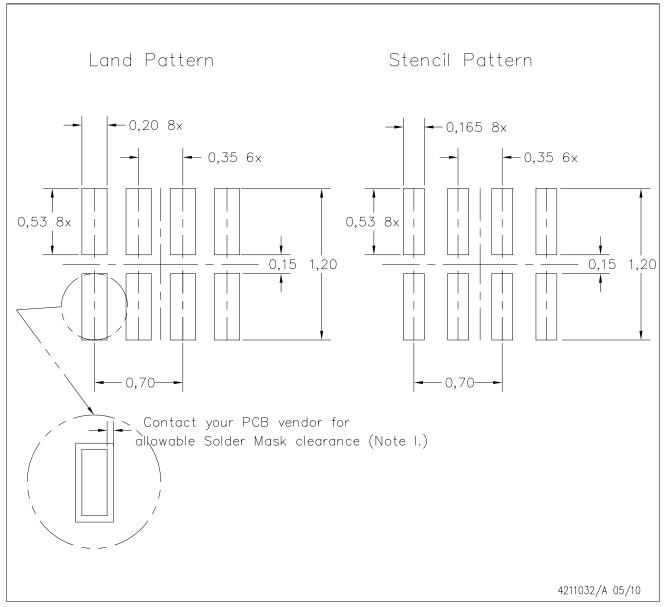
NOTES: All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
  C. SON (Small Outline No-Lead) package configuration.
  D. This package complies to JEDEC MO-287 variation X2EAF.



DQE (R-PX2SON-N8)

PLASTIC SMALL OUTLINE NO-LEAD



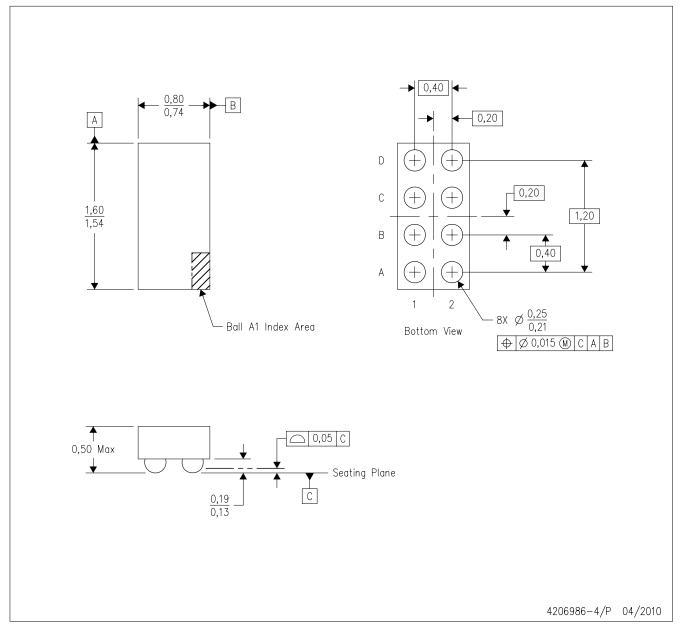
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads. If 2 mil solder mask is outside PCB vendor capability, it is advised to omit solder mask.
- E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Over—printing land for acceptable area ratio is not viable due to land width and bridging potential. Customer may further reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.
- H. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
- I. Component placement force should be minimized to prevent excessive paste block deformation.



YFP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This is a Pb-free solder ball design.

NanoFree is a trademark of Texas Instruments.



#### IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Audio	www.ti.com/audio	Communications and Telecom	www.ti.com/communications
Amplifiers	amplifier.ti.com	Computers and Peripherals	www.ti.com/computers
Data Converters	dataconverter.ti.com	Consumer Electronics	www.ti.com/consumer-apps
DLP® Products	www.dlp.com	Energy and Lighting	www.ti.com/energy
DSP	dsp.ti.com	Industrial	www.ti.com/industrial
Clocks and Timers	www.ti.com/clocks	Medical	www.ti.com/medical
Interface	interface.ti.com	Security	www.ti.com/security
Logic	logic.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Power Mgmt	power.ti.com	Transportation and Automotive	www.ti.com/automotive
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com	Wireless	www.ti.com/wireless-apps
RF/IF and ZigBee® Solutions	www.ti.com/lprf		

**TI E2E Community Home Page** 

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2011, Texas Instruments Incorporated

e2e.ti.com